

Dual Piccoampere Input Current Bipolar Qo Amp

AD706

FEATURE

HIGH DC PRECISION
50 μV max Offset Voltage
0.6 μV/°C max Offset Drift
110 pA max Input Bias Current

LOW NOISE 0.5 μ V p-p Voltage Noise, 0.1 Hz to 10 Hz

LOW POWER
750 µA Supply Current
Available in 8-Lead Plastic Mini-DIP, Hermetic Cerdip
and Surface Mount (SOIC) Packages
Available in Tape and Reel in Accordance with
EIA-481A Standard
Single Version: AD705, Quad Version: AD704

PRIMARY APPLICATIONS
Low Frequency Active Filters
Precision Instrumentation
Precision Integrators

PRODUCT DESCRIPTION

The AD706 is a dual, low power, bipolar op amp that has the low input bias current of a BiFET amplifier, but which offers a significantly lower I_B drift over temperature. It utilizes superbeta bipolar input transistors to achieve picoampere input bias current levels (similar to FET input amplifiers at room temperature), while its I_B typically only increases by 5× at 125°C (unlike a BiFET amp, for which I_B doubles every 10°C for a 1000× increase at 125°C). The AD706 also achieves the microvolt offset voltage and low noise characteristics of a precision bipolar input amplifier.

Since it has only 1/20 the input bias current of an OP07, the AD706 does not require the commonly used "balancing" resistor. Furthermore, the current noise is 1/5 that of the OP07, which makes this amplifier usable with much higher source impedances. At 1/6 the supply current (per amplifier) of the OP07, the AD706 is better suited for today's higher density boards.

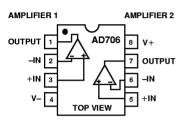
The AD706 is an excellent choice for use in low frequency active filters in 12- and 14-bit data acquisition systems, in precision instrumentation and as a high quality integrator. The AD706 is internally compensated for unity gain and is available in five performance grades. The AD706J and AD706K are rated over the commercial temperature range of 0°C to +70°C. The AD706A and AD706B are rated over the industrial temperature range of -40°C to +85°C.

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CONNECTION DIAGRAM

Plastic Mini-DIP (N)
Cerdip (Q) and
Plastic SOIC (R) Packages



The AD706 is offered in three varieties of an 8-lead package: plastic mini-DIP, hermetic cerdip and surface mount (SOIC). "J" grade chips are also available.

PRODUCT HIGHLIGHTS

- 1. The AD706 is a dual low drift op amp that offers BiFET level input bias currents, yet has the low I_B drift of a bipolar amplifier. It may be used in circuits using dual op amps such as the LT1024.
- 2. The AD706 provides both low drift and high dc precision.
- 3. The AD706 can be used in applications where a chopper amplifier would normally be required but without the chopper's inherent noise.

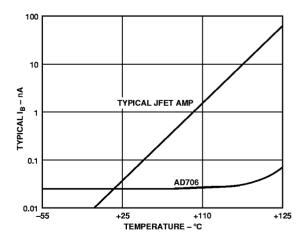


Figure 1. Input Bias Current vs. Temperature

Parameter	Conditions	AD 706J/A Min Typ Max	AD 706K/B Min Typ Max	Units
INPUT OFFSET VOLTAGE				
Initial Offset		30 100	10 50	μV
Offset	T _{MIN} to T _{MAX}	40 150	25 100	μV
vs. Temp, Average TC	I MIN TO I MAX	0.2 1.5	0.2 0.6	μV/°C
vs. Supply (PSRR)	$V_{S} = \pm 2 \text{ V to } \pm 18 \text{ V}$	110 132	112 132	dB
T_{MIN} to T_{MAX}	$V_S = \pm 2.5 \text{ V to } \pm 18 \text{ V}$	106 126	108 126	dB
Long Term Stability	75 = 22.5 7 10 210 7	0.3	0.3	μV/M on th
INPUT BIAS CURRENT ¹		1		p , i.i.z o i.i.z
INPUT BIAS CURRENT	$V_{CM} = 0 V$	50 200	30 110	
	$V_{CM} = 0 \text{ V}$ $V_{CM} = \pm 13.5 \text{ V}$	250	30 110	pA
vs. Temp, Average TC	$v_{\rm CM} = \pm 13.3 \text{ V}$	0.3	0.2	pA pA/°C
T_{MIN} to T_{MAX}	$V_{CM} = 0 V$	300	200	
		400	300	pA
T_{MIN} to T_{MAX}	$V_{CM} = \pm 13.5 \text{ V}$			pА
INPUT OFFSET CURRENT	$V_{CM} = 0 V$	30 150	30 100	pA
	$V_{CM} = \pm 13.5 \text{ V}$	250	200	pA
vs. Temp, Average TC		0.6	0.4	pA/°C
T_{MIN} to T_{MAX}	$V_{CM} = 0 V$	80 250	80 200	pA
T_{MIN} to T_{MAX}	$V_{CM} = \pm 13.5 \text{ V}$	80 350	80 300	pA
MATCHING CHARACTERISTICS				
Offset Voltage		150	75	μV
<i>5</i>	T _{MIN} to T _{MAX}	250	150	μV
Input Bias Current ²	MIN MAX	300	150	pA
1	T _{MIN} to T _{MAX}	500	250	pA
Common-Mode Rejection	- MIN MAX	106	110	dB
3	T_{MIN} to T_{MAX}	106	108	dB
Power Supply Rejection	MIN MAA	106	110	dB
	T _{MIN} to T _{MAX}	104	106	dB
Crosstalk	@ $f = 10 \text{ Hz}$			
(Figure 19a)	$R_L = 2 k\Omega$	150	150	dB
	1			
FREQUENCY RESPONSE				
Unity Gain Crossover		0.8	0.8	MHz
Frequency Slew Rate	G = -1	0.8	0.8	V/µs
Siew Rate				
	T _{MIN} to T _{MAX}	0.15	0.15	V/µs
INPUT IMPEDANCE				
D ifferential		40 2	40 2	MΩ pF
Common Mode		300 2	300 2	GΩ pF
INPUT VOLTAGE RANGE				
Common-Mode Voltage		±13.5 ±14	±13.5 ±14	V
Common-Mode Rejection				
Ratio	$V_{CM} = \pm 13.5 \text{ V}$	110 132	114 132	dB
	T _{MIN} to T _{MAX}	108 128	108 128	dB
INDUE CUDDENT NOISE	0.1 Hz to 10 Hz	3	3	
INPUT CURRENT NOISE				pAp-p
	f = 10 Hz	50	50	fA/√Hz
INPUT VOLTAGE NOISE	0.1 Hz to 10 Hz	0.5	0.5 1.0	μV p <u>-p</u>
	f = 10 Hz	17	17	nV/√ Hz
	f = 1 kHz	15 22	15 22	nV/√Hz
OPEN-LOOP GAIN	$V_0 = \pm 12 \text{ V}$			
	$R_{LOAD} = 10 \text{ k}\Omega$	200 2000	400 2000	V/m V
	T_{MIN} to T_{MAX}	150 1500	300 1500	V/m V
	$V_O = \pm 10 \text{ V}$			
	$R_{LOAD} = 2 k\Omega$	200 1000	300 1000	V/m V
	T_{MIN} to T_{MAX}	150 1000	200 1000	V/m V
OTTEDLE OF AD ACTEDIOTION	- IVIIII IVIAA	1	1	.,
OUTPUT CHARACTERISTICS	D 1010	1 112	112	
Voltage Swing	$R_{LOAD} = 10 \text{ k}\Omega$	±13 ±14	±13 ±14	V
	T _{MIN} to T _{MAX}	±13 ±14	±13 ±14	V .
Current	Short Circuit	±15	±15	m A
Capacitive Load				_
Drive Capability	Gain = +1	10,000	10,000	pF

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		AD 706J/A			AD 706K/B				
Parameter	Conditions	Min	Тур	Max	Min	Тур	Max	Units	
POWER SUPPLY									
Rated Performance			±15			±15		V	
Operating Range		±2.0		± 18	±2.0		±18	V	
Quiescent Current, Total			0.75	1.2		0.75	1.2	m A	
	T _{MIN} to T _{MAX}		0.8	1.4		0.8	1.4	m A	
FRANSISTOR COUNT	# of Transistors		90			90			

NOTES

CMRR match is the difference between $\frac{\Delta V_{OS} \# I}{\Delta V_{CM}}$ for amplifier #1 and $\frac{\Delta V_{OS} \# 2}{\Delta V_{CM}}$ for amplifier #2 expressed in dB.

PSRR match is the difference between $\frac{\Delta V_{OS} \# 1}{\Delta V_{SUPPLY}}$ for amplifier #1 and $\frac{\Delta V_{OS} \# 2}{\Delta V_{SUPPLY}}$ for amplifier #2 expressed in dB.

All min and max specifications are guaranteed. Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS¹

Supply Voltage
Internal Power Dissipation
(Total: Both Amplifiers) ² 650 mW
Input Voltage
Differential Input Voltage ³ +0.7 Volts
Output Short Circuit Duration Indefinite
Storage Temperature Range (Q)65°C to +150°C
Storage Temperature Range (N, R)65°C to +125°C
Operating Temperature Range
AD706J/K 0°C to +70°C
AD706A/B40°C to +85°C
Lead Temperature (Soldering 10 secs) +300°C

NOTES

8-Lead Cerdip Package: $\theta_{IA}=110^{\circ}\text{C/Watt}$ 8-Lead Small Outline Package: $\theta_{IA}=155^{\circ}\text{C/Watt}$

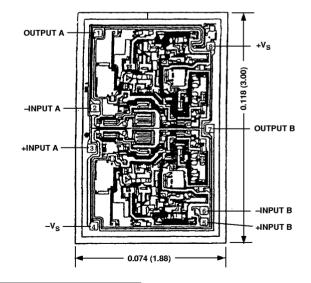
ORDERING GUIDE

Model	Tem perature Range	Description	Package Option*
AD706AN	−40°C to +85°C	Plastic DIP	N-8
AD706JN	0° C to $+70^{\circ}$ C	Plastic DIP	N-8
AD706KN	0°C to +70°C	Plastic DIP	N-8
AD706JR	0° C to $+70^{\circ}$ C	SOIC	R-8
AD706JR-REEL	0°C to +70°C	Tape and Reel	
AD706AQ	-40°C to $+85$ °C	Cerdip	Q-8
AD706BQ	−40°C to +85°C	Cerdip	Q-8
AD706AR	−40°C to +85°C	SOIC	R-8
AD706AR-REEL	-40° C to $+85^{\circ}$ C	Tape and Reel	

^{*}N = Plastic DIP; Q = Cerdip, R = Small Outline Package.

METALIZATION PHOTOGRAPH

Dimensions shown in inches and (mm). Contact factory for latest dimensions.



CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD706 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



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¹Bias current specifications are guaranteed maximum at either input.

²Input bias current match is the difference between corresponding inputs (I_B of -IN of Amplifier #1 minus I_B of -IN of Amplifier #2).

¹Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

²Specification is for device in free air:

⁸⁻Lead Plastic Package: $\theta_{JA} = 100^{\circ}\text{C/Watt}$

³The input pins of this amplifier are protected by back-to-back diodes. If the differential voltage exceeds ±0.7 volts, external series protection resistors should be added to limit the input current to less than 25 mA.

AD706-Typical Characteristics (@+25°C, V_S = ±15 V, unless otherwise noted)

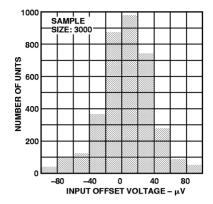


Figure 2. Typical Distribution of Input Offset Voltage

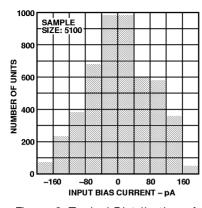


Figure 3. Typical Distribution of Input Bias Current

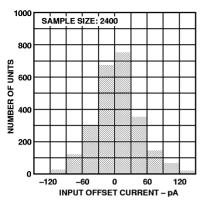


Figure 4. Typical Distribution of Input Offset Current

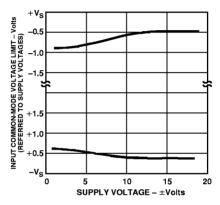


Figure 5. Input Common-Mode Voltage Range vs. Supply Voltage

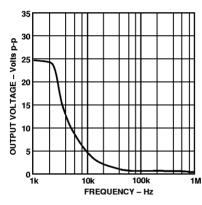


Figure 6. Large Signal Frequency Response

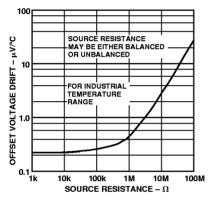


Figure 7. Offset Voltage Drift vs. Source Resistance

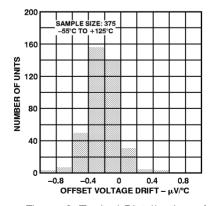


Figure 8. Typical Distribution of Offset Voltage Drift

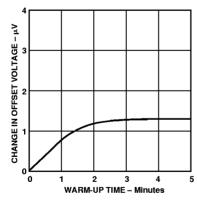


Figure 9. Change in Input Offset Voltage vs. Warm-Up Time

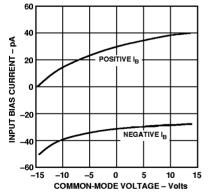


Figure 10. Input Bias Current vs. Common-Mode Voltage

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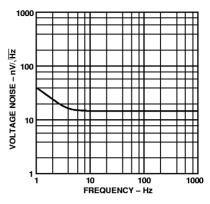
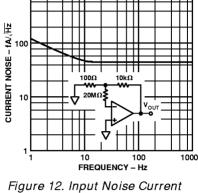


Figure 11. Input Noise Voltage Spectral Density



1000

Figure 12. Input Noise Current Spectral Density

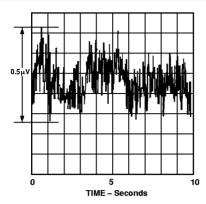


Figure 13. 0.1 Hz to 10 Hz Noise Voltage

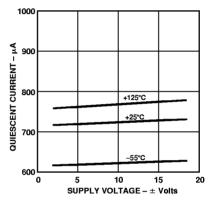


Figure 14. Quiescent Supply Current vs. Supply Voltage

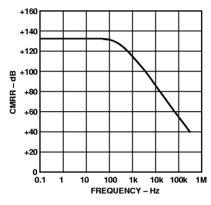


Figure 15. Common-Mode Rejection Ratio vs. Frequency

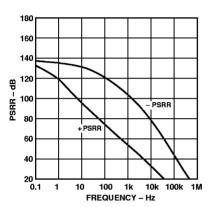


Figure 16. Power Supply Rejection Ratio vs. Frequency

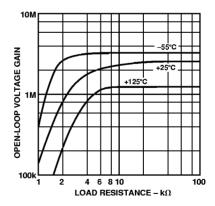


Figure 17. Open-Loop Gain vs. Load Resistance vs. Load Resistance

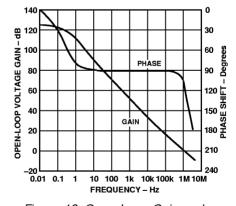


Figure 18. Open-Loop Gain and Phase Shift vs. Frequency

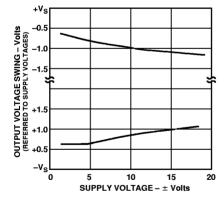


Figure 19. Output Voltage Swing vs. Supply Voltage

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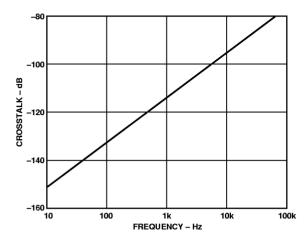


Figure 20a. Crosstalk vs. Frequency

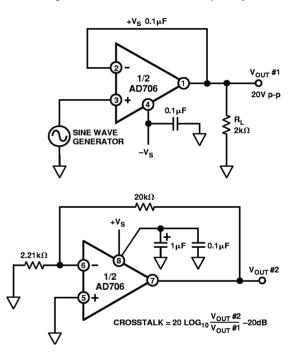


Figure 20b. Crosstalk Test Circuit

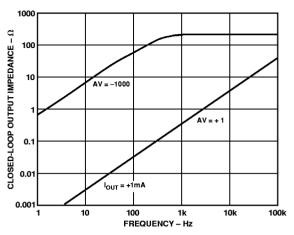


Figure 21. Magnitude of Closed-Loop Output Impedance vs. Frequency

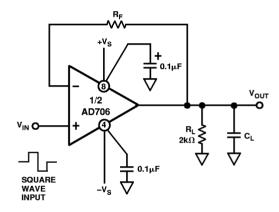


Figure 22a. Unity Gain Follower (For Large Signal Applications, Resistor R_F Limits the Current Through the Input Protection Diodes)

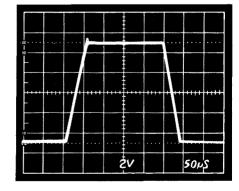


Figure 22b. Unity Gain Follower Large Signal Pulse Response, $R_F = 10 \text{ k}\Omega$, $C_L = 1,000 \text{ pF}$

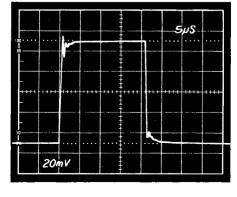


Figure 22c. Unity Gain Follower Small Signal Pulse Response, $R_F = 0 \Omega$, $C_L = 100 pF$

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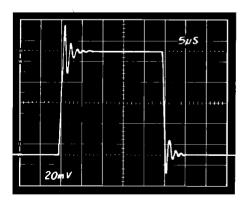


Figure 22d. Unity Gain Follower Small Signal Pulse Response, $R_F = 0 \Omega$, $C_L = 1000 pF$

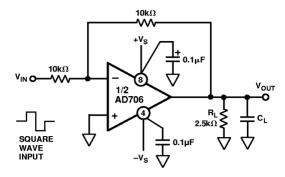
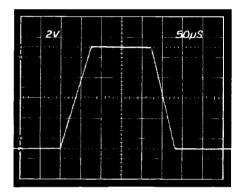
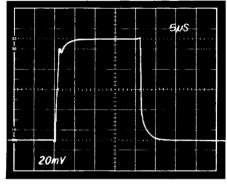


Figure 23a. Unity Gain Inverter Connection





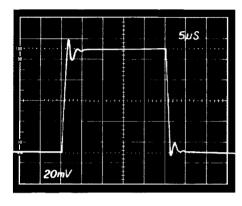


Figure 23b. Unity Gain Inverter Large Signal Pulse Response, $C_L = 1,000 pF$

Figure 23c. Unity Gain Inverter Small Signal Pulse Response, $C_L = 100 \text{ pF}$

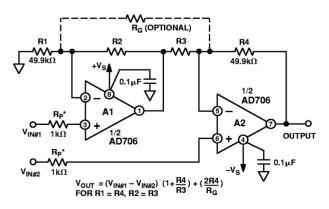
Figure 23d. Unity Gain Inverter Small Signal Pulse Response, $C_L = 1000 \text{ pF}$

Figure 24 shows an in-amp circuit that has the obvious advantage of requiring only one AD706, rather than three op amps, with subsequent savings in cost and power consumption. The transfer function of this circuit (without $R_{\rm G}$) is:

$$V_{OUT} = (V_{IN \# 1} - V_{IN \# 2}) \left(1 + \frac{R4}{R3}\right)$$

 $for R1 = R4 \ and \ R2 = R3$

Input resistance is high, thus permitting the signal source to have an unbalanced output impedance.



*OPTIONAL INPUT PROTECTION RESISTOR FOR GAINS GREATER THAN 100 OR INPUT VOLTAGES EXCEEDING THE SUPPLY VOLTAGE.

Figure 24. A Two Op-Amp Instrumentation Amplifier
Furthermore, the circuit gain may be fine trimmed using an optional trim resistor, R_G. Like the three op-amp circuit, CMR

increases with gain, once initial trimming is accomplished—but CMR is still dependent upon the ratio matching of Resistors R1 through R4. Resistor values for this circuit, using the optional gain resistor, R_G, can be calculated using:

$$R1 = R4 = 49.9 k\Omega$$

$$R2 = R3 = \frac{49.9 k\Omega}{0.9 G - 1}$$

$$R_G = \frac{99.8 k\Omega}{0.06 G}$$

where $G = Desired\ Circuit\ Gain$

Table I provides practical 1% resistance values. (Note that without resistor $R_G,\,R2$ and R3 = 49.9 kΩ/G–1.)

Table I. Operating Gains of Amplifiers A1 and A2 and Practical 1% Resistor Values for the Circuit of Figure 24

Circuit Gain	Gain of A1	Gain of A2	R2, R3	R1, R4
1.10	11.00	1.10	499 kΩ	49.9 kΩ
1.33	4.01	1.33	150 kΩ	49.9 kΩ
1.50	3,00	1.50	100 kΩ	49.9 kΩ
2.00	2.00	2.00	49.9 kΩ	49.9 kΩ
10.1	1.11	10.10	5.49 kΩ	49.9 kΩ
101.0	1.01	101.0	499 Ω	49.9 kΩ
1001	1.001	1001	49.9 Ω	49.9 kΩ

For a much more comprehensive discussion of in-amp applications, refer to the *Instrumentation Amplifier Applications Guide*—available free from Analog Devices, Inc.

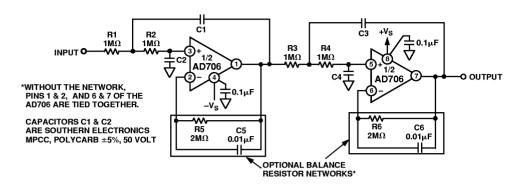


Figure 25. A 1 Hz, 4-Pole Active Filter

A 1 Hz, 4-Pole, Active Filter

Figure 25 shows the AD706 in an active filter application. An important characteristic of the AD706 is that both the input bias current, input offset current and their drift remain low over most of the op amp's rated temperature range. Therefore, for most applications, there is no need to use the normal balancing resistor. Adding the balancing resistor enhances performance at high temperatures, as shown by Figure 26.

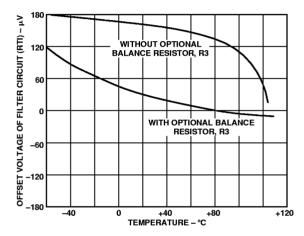


Figure 26. V_{OS} vs. Temperature Performance of the 1 Hz Filter

Table II. 1 Hz, 4-Pole, Low Pass Filter Recommended Component Values

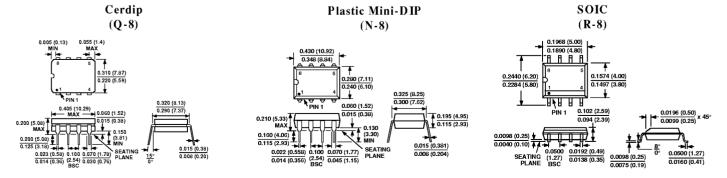
Desired Low Pass Response	Section 1 Frequency (Hz)	Q	Section 2 Frequency (Hz)	Q	C1 (µF)	C2 (µF)	C3 (µF)	C4 (µF)
Bessel	1.43	0.522	1.60	0.806	0.116	0.107	0.160	0.0616
Butterworth	1.00	0.541	1.00	1.31	0.172	0.147	0.416	0.0609
0.1 dB Chebychev	0.648	0.619	0.948	2.18	0.304	0.198	0.733	0.0385
0.2 dB Chebychev	0,603	0,646	0.941	2.44	0.341	0.204	0.823	0.0347
0.5 dB Chebychev	0.540	0.705	0.932	2.94	0.416	0.209	1.00	0.0290
1.0 dB Chebychev	0.492	0.785	0.925	3,56	0.508	0.206	1.23	0,0242

NOTE

Specified Values are for a -3 dB point of 1.0 Hz. For other frequencies simply scale capacitors C1 through C4 directly, i.e.: for 3 Hz Bessel response, C1 = 0.0387 μ F, C2 = 0.0357 μ F, C3 = 0.0533 μ F, C4 = 0.0205 μ F.

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).



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